

Pb Free Plating Product

HER501 thru HER508



5.0 Ampere Open Junction High Efficiency Rectifier Diode

Features

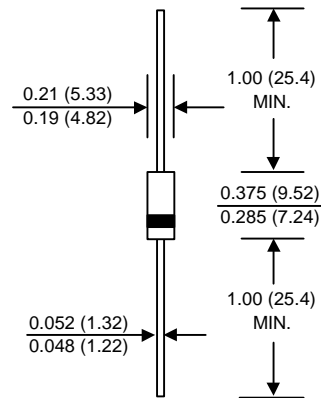
- ✧ High efficiency, Low VF
- ✧ High current capability
- ✧ High reliability
- ✧ High surge current capability
- ✧ For use in low voltage, high frequency inverter, free wheeling, and polarity protection application.

Mechanical Data

- ✧ Cases: Molded plastic
- ✧ Epoxy: UL 94V-0 rate flame retardant
- ✧ Lead: Pure tin plated, lead free, solderable per MIL-STD-202, Method 208 guaranteed
- ✧ Polarity: Color band denotes cathode
- ✧ High temperature soldering guaranteed: 260°C/10 seconds/.375", (9.5mm) lead lengths at 5 lbs., (2.3kg) tension
- ✧ Weight: 1.16 grams

DO-201AD

Unit: inch(mm)



Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	HER 501	HER 502	HER 503	HER 504	HER 505	HER 506	HER 507	HER 508	Units	
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	300	400	600	800	1000	V	
Maximum RMS Voltage	V_{RMS}	35	70	140	210	280	420	560	700	V	
Maximum DC Blocking Voltage	V_{DC}	50	100	200	300	400	600	800	1000	V	
Maximum Average Forward Rectified Current .375 (9.5mm) Lead Length @ $T_A = 55^\circ C$	$I_{(AV)}$	5.0								A	
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	200								A	
Maximum Instantaneous Forward Voltage @ 5.0A	V_F	1.0			1.3		1.7			V	
Maximum DC Reverse Current @ $T_A=25^\circ C$ at Rated DC Blocking Voltage @ $T_A=125^\circ C$	I_R	10 250								μA μA	
Maximum Reverse Recovery Time (Note 1)	T_{rr}	50					75				nS
Typical Junction capacitance (Note 2)	C_j	130					85				pF
Typical Thermal Resistance	$R_{\theta JA}$	30									$^\circ C/W$
Operating Temperature Range	T_J	-65 to +150									$^\circ C$
Storage Temperature Range	T_{STG}	-65 to +150									$^\circ C$

- Notes:
1. Reverse Recovery Test Conditions: $I_F=0.5A$, $I_R=1.0A$, $I_{RR}=0.25A$
 2. Measured at 1 MHz and Applied Reverse Voltage of 4.0 V D.C.
 3. Mount on Cu-Pad Size 16mm x 16mm on PCB.

RATING AND CHARACTERISTIC CURVES (HER501 - HER508)

FIG.1 - REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

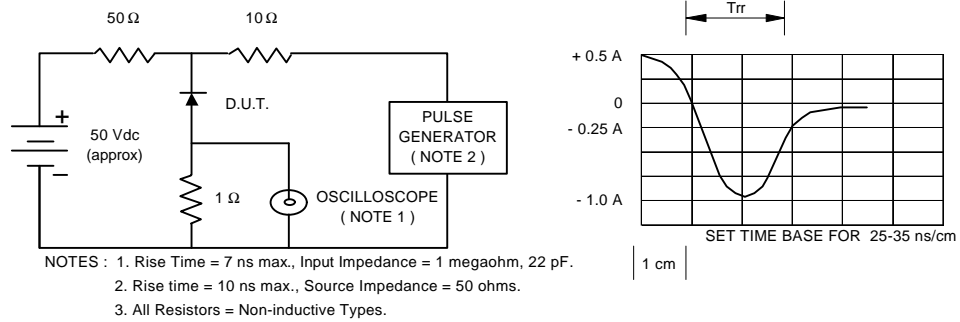


FIG.2 - DERATING CURVE FOR OUTPUT RECTIFIED CURRENT

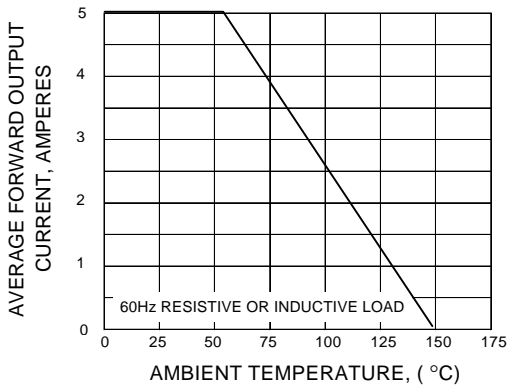


FIG.3 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

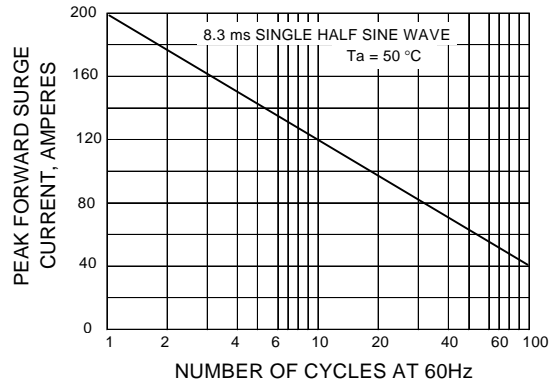


FIG.4 - TYPICAL FORWARD CHARACTERISTICS

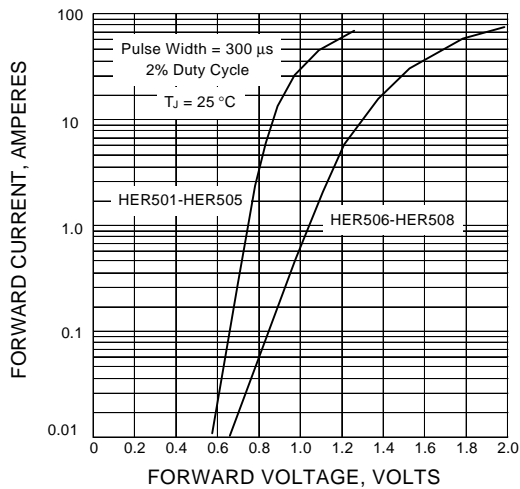


FIG.5 - TYPICAL REVERSE CHARACTERISTICS

